



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C |
|-------------------|--------------------------------|--|
| 001/ | 45mΩ @ V _{GS} = -4.5V | -4.7A |
| -20V | 90mΩ @ V _{GS} = -1.8V | -3.3A |

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: X2-DFN2015-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



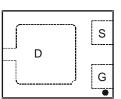


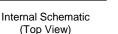


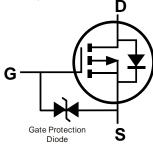
ESD protected Gate

TOP VIEW

BOTTOM VIEW







Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---------------|--------------|-------------------|
| DMP2045UFY4-7 | X2-DFN2015-3 | 3,000/Tape & Reel |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



45F = Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

| Bate Bode He | - / | | | | | | | | | | | |
|--------------|------|------|-----|-----|------|------|-----|------|------|-----|-----|------|
| Year | 2017 | 2018 | 20 | 019 | 2020 | 2021 | | 2022 | 2023 | 202 | 24 | 2025 |
| Code | E | F | (| G | Н | I | | J | K | L | - | М |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit | |
|--|-----------------|--|-------|--------------|---|
| Drain-Source Voltage | | V _{DSS} | -20 | V | |
| Gate-Source Voltage | | V _{GSS} | ±8 | V | |
| Continuous Drain Current (Note 6) V_{GS} = -4.5V | Steady State | T _A = +25°C T _A = +70°C | ID | -4.7 -3.8 | A |
| Maximum Continuous Body Diode Forward Curre | ent (Note 6) | Is | -1 | А | |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = | 1%) | I _{DM} | -25 | А | |

Thermal Characteristics

| Characteristic | | Symbol | Value | Unit |
|--|-----------------|-----------------|-------------|------|
| Total Power Dissipation (Note 5) | | PD | 0.67 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | $R_{	heta}JA$ | 190 | °C/W |
| Total Power Dissipation (Note 6) | | PD | 1.49 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | $R_{	hetaJA}$ | 84 | °C/W | |
| Thermal Resistance, Junction to Case (Note 6) | | $R_{\theta JC}$ | 14.5 | |
| Operating and Storage Temperature Range | | TJ, TSTG | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

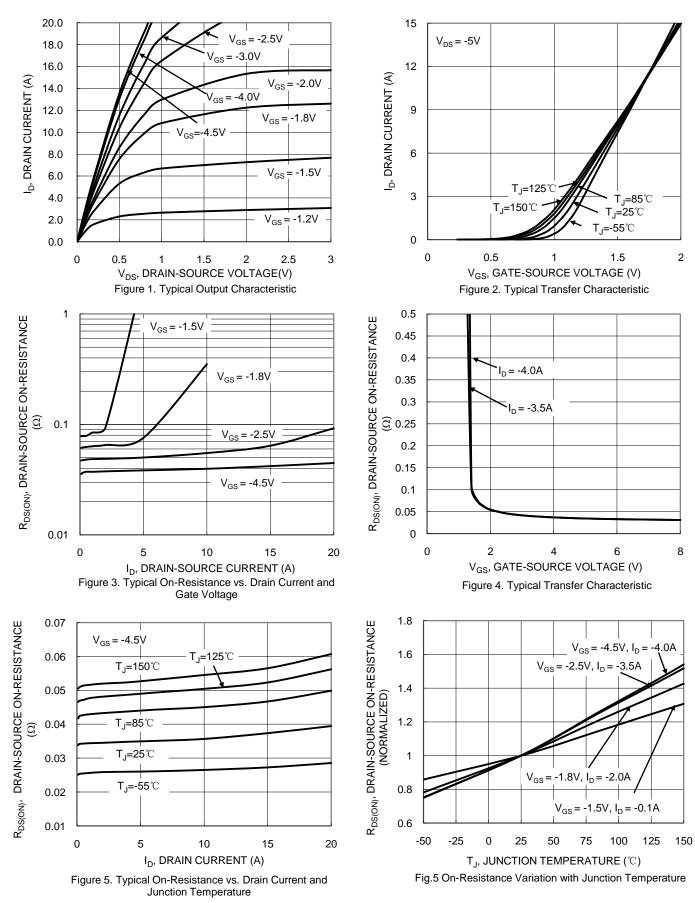
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|---------------------|------|------|------|-------|---|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | | _ | V | $V_{GS} = 0V, I_D = -250 \mu A$ |
| Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$ | I _{DSS} | _ | _ | -1 | μA | $V_{DS} = -20V, V_{GS} = 0V$ |
| Gate-Source Leakage | I _{GSS} | _ | _ | ±10 | μA | $V_{GS} = \pm 8.0V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.3 | _ | -1.0 | V | $V_{DS} = V_{GS}, I_{D} = -250 \mu A$ |
| | | _ | 34 | 45 | | $V_{GS} = -4.5V, I_{D} = -4.0A$ |
| Static Drain-Source On-Resistance | D | _ | 44 | 58 | mΩ | V _{GS} = -2.5V, I _D = -3.5A |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 56 | 90 | 11122 | V _{GS} = -1.8V, I _D = -0.1A |
| | | _ | 80 | 160 | | $V_{GS} = -1.5V, I_D = -0.1A$ |
| Diode Forward Voltage | V _{SD} | _ | -0.6 | -1.2 | V | $V_{GS} = 0V, I_{S} = 1.0A$ |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | Ciss | — | 634 | _ | pF | |
| Output Capacitance | Coss | _ | 81 | _ | pF | V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz |
| Reverse Transfer Capacitance | Crss | _ | 66 | _ | pF | |
| Gate Resistance | Rg | _ | 20 | — | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$ |
| Total Gate Charge | Qg | _ | 6.8 | — | nC | |
| Gate-Source Charge | Q _{gs} | _ | 0.7 | _ | nC | V _{GS} = -4.5V, V _{DS} = -10V I _D = -4A |
| Gate-Drain Charge | Q _{gd} | _ | 1.6 | _ | nC | 1D = -4A |
| Turn-On Delay Time | t _{D(ON)} | _ | 4.2 | _ | ns | |
| Turn-On Rise Time | t _R | _ | 3.4 | | ns | V _{DS} = -10V, V _{GS} = -4.5V, |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 22.7 | _ | ns | $R_D = 2.5\Omega, R_g = 3.0\Omega, I_D = -1A$ |
| Turn-Off Fall Time | t _F | _ | 9.6 | — | ns | 1 |
| Reverse Recovery Time | t _{RR} | _ | 1.8 | _ | ns | I _F = -1.0A, di/dt = 100A/µs |
| Reverse Recovery Charge | Q _{RR} | _ | 9.4 | _ | nC | I _F = -1.0A, di/dt = 100A/µs |

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

Schot duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

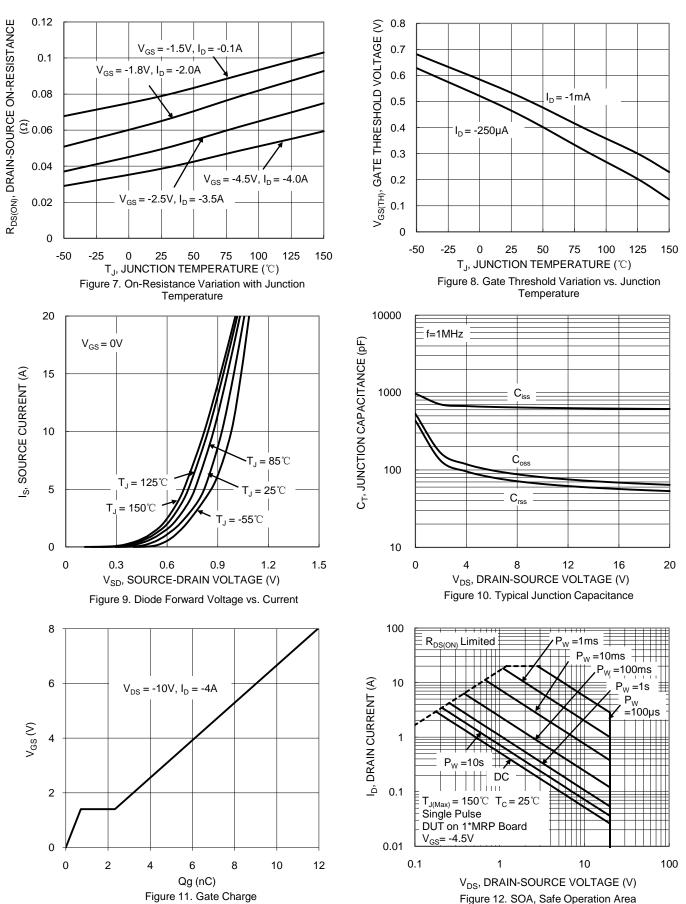


DMP2045UFY4

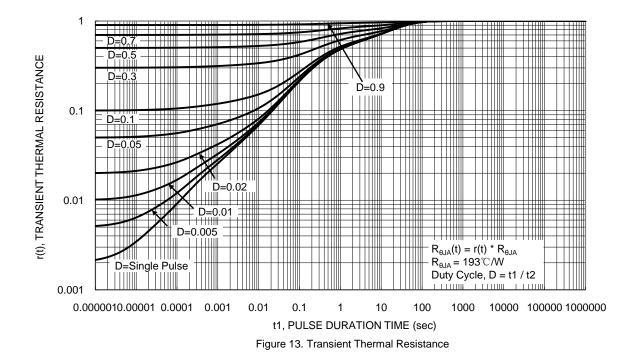




DMP2045UFY4





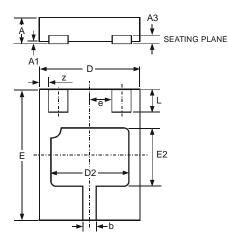




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

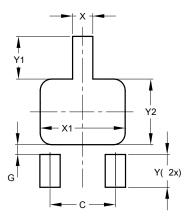
X2-DFN2015-3



| | X2-DFN2015-3 | | | | | | | |
|-----|--------------|-------|-------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| Α | - | 0.40 | - | | | | | |
| A1 | 0 | 0.05 | 0.02 | | | | | |
| A3 | 1 | 1 | 0.13 | | | | | |
| b | 0.20 | 0.30 | 0.25 | | | | | |
| D | 1.45 | 1.575 | 1.5 | | | | | |
| D2 | 1.00 | 1.20 | 1.10 | | | | | |
| е | 1 | 1 | 0.50 | | | | | |
| E | 1.95 | 2.075 | 2.00 | | | | | |
| E2 | 0.70 | 0.90 | 0.80 | | | | | |
| L | 0.25 | 0.35 | 0.30 | | | | | |
| z | - | - | 0.125 | | | | | |
| All | Dimen | sions | in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



X2-DFN2015-3

| X2-DFN2015-3 | | | | | |
|--------------|------------------|--|--|--|--|
| Dimensions | Value (in mm) | | | | |
| С | 1.000 | | | | |
| G | 0.150 | | | | |
| Х | 0.310 | | | | |
| X1 | 1.300 | | | | |
| Ý | 0.500 | | | | |
| Y1 | 0.650 | | | | |
| Y2 | 1.000 | | | | |



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